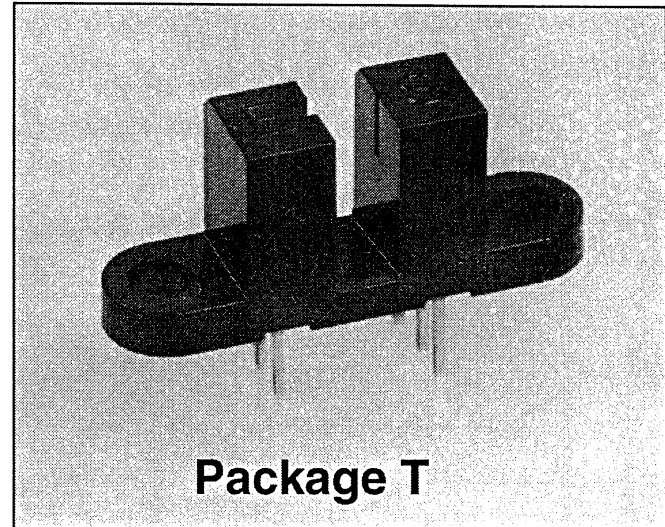
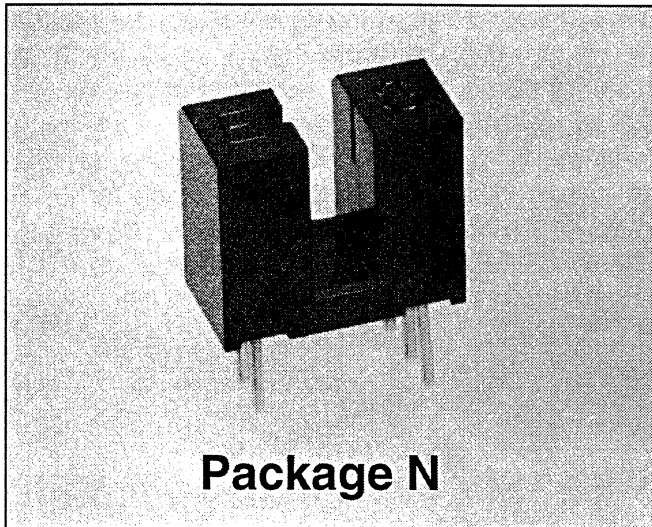


Photologic[®] Slotted Optical Switch

Types OPB665N/T, OPB666N/T, OPB667N/T, OPB668N/T



Features

- Four Output Options
- 0.125" (3.18 mm) Wide Gap
- 0.320" (8.13 mm) Lead Spacing
- N or T Package
- 0.010" Sensor Aperture

Description

The OPB665 series optical switches consist of a monolithic integrated circuit and an infrared emitting diode mounted on opposite sides of a 0.125" (3.18 mm) wide slot. The emitter has a 0.050" x 0.060" molded-in aperture while the sensor has a 0.010" x 0.060" molded-in aperture.

The device features TTL/LSTTL compatible logic level output, which can drive up to 10 TTL loads over a voltage range from 4.5 V to 16 V.

Absolute Maximum Ratings (T_A = 25° C unless otherwise noted)

Storage Temperature Range	-40° C to +100° C
Operating Temperature Range	-40° C to +100° C
Lead Soldering Temperature [1/16 inch (1.6 mm) from case for 5 sec. with soldering iron]	240° C ⁽¹⁾

Input Diode

Forward DC Current	50 mA
Peak Forward Current (1μs pulse width, 300 pps)	3.0 A
Reverse DC Voltage	3.0 V
Power Dissipation	100 mW ⁽²⁾

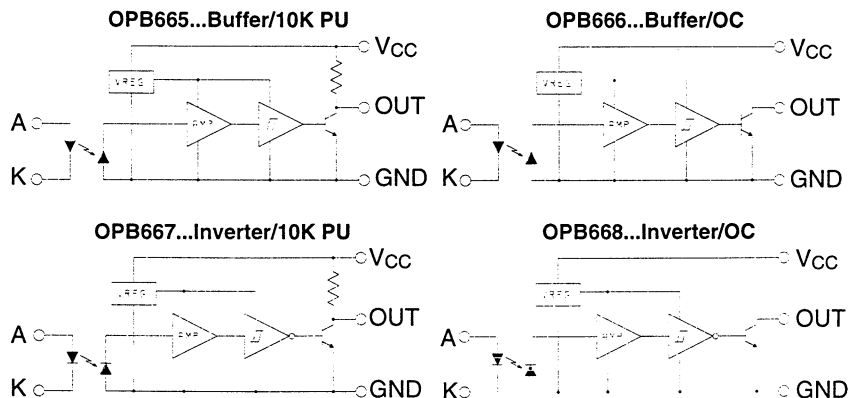
Output Photologic[®]

Supply Voltage, V _{CC}	18 V
Duration of Output Short To V _{CC}	1.0 sec
Voltage at Output	30 V
Low Level Output Current (sinking)	16 mA
Power Dissipation	240 mW ⁽³⁾

Notes:

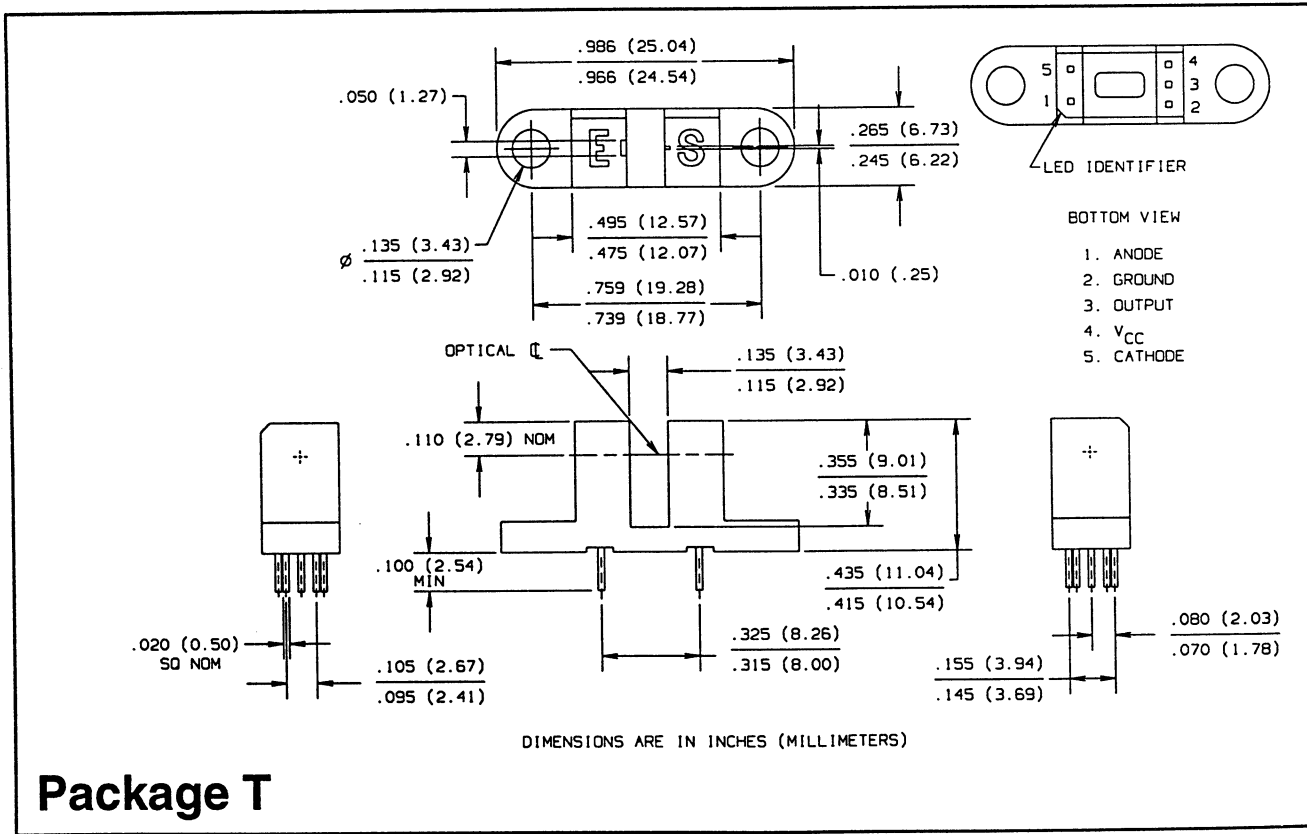
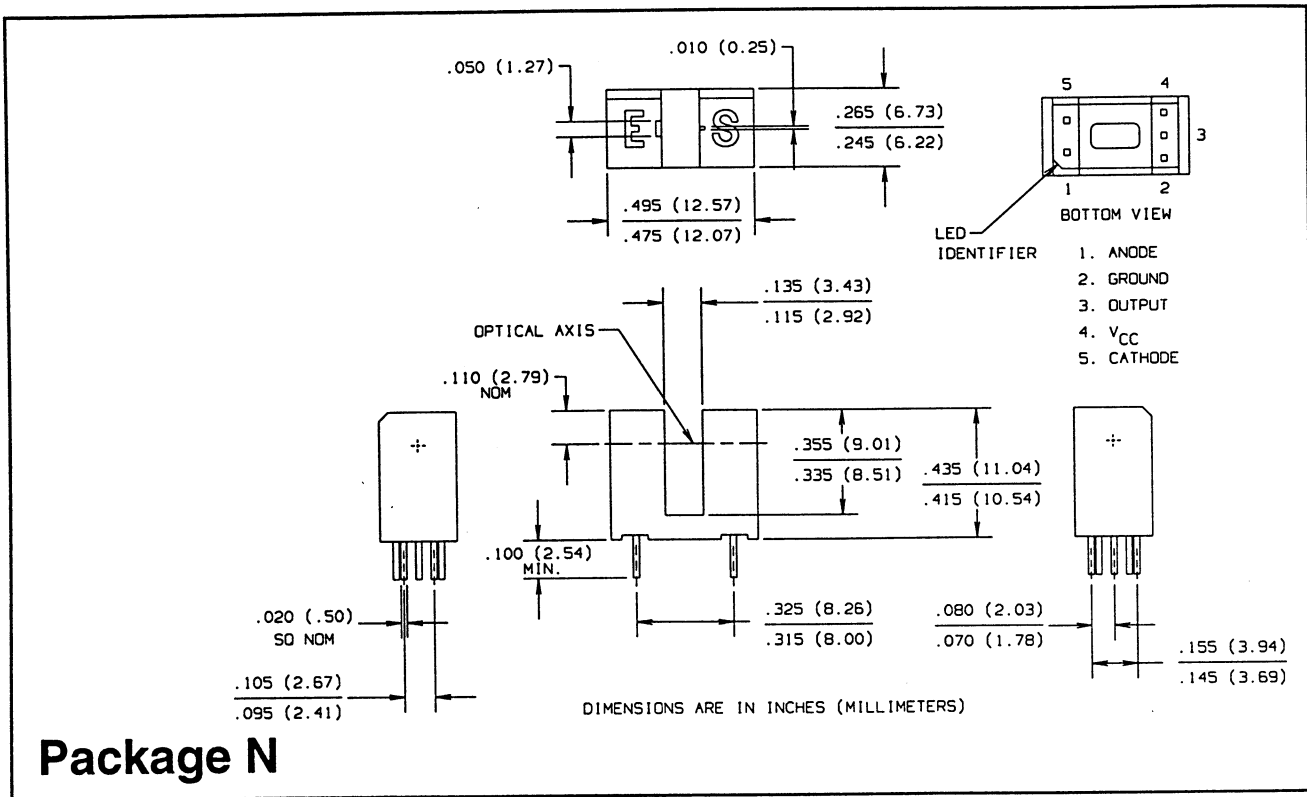
- (1) RMA flux is recommended. Duration can be extended to 10 sec. max. when flow soldering.
- (2) Derate linearly 1.33 mW/° C above 25° C.
- (3) Derate linearly 2.50 mW/° C above 30° C.

Schematics



Types OPB665N/T, OPB666N/T, OPB667N/T, OPB668N/T

SLOTTED OPTICAL SWITCHES



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Types OPB665N/T, OPB666N/T, OPB667N/T, OPB668N/T

Electrical Characteristics ($T_A = 25^\circ\text{C}$ unless otherwise noted)

SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS
Input Diode						
V_F	Forward Voltage			1.6	V	$I_F = 10\text{ mA}$
I_R	Reverse Current			100	μA	$V_R = 3.0\text{ V}$
Output Photologic™ Sensor						
V_{CC}	Operating D.C. Supply Voltage	4.5		16.0	V	
$I_F(+)$	LED Positive-Going Threshold Current	0.1	1.6	10	mA	$V_{CC} = 5.0\text{ V}$
$I_F(+)/I_F(-)$	Hysteresis Ratio	1.05	1.20	1.60		$V_{CC} = 5.0\text{ V}$
I_{CCH}	High Level Supply Current:					
	Buffer, 10K Pull-up OPB665 Buffer, Open-Collector OPB666		5.0	12.0	mA	$V_{CC} = 16\text{ V}$, No Load On Output, $I_F = 10\text{ mA}$
I_{CCH}	Inverter, 10K Pull-up OPB667 Inverter, Open-Collector OPB668		4.0	12.0	mA	$V_{CC} = 16\text{ V}$, No Load On Output, $I_F = 0\text{ mA}$
	I_{CCL}	Low Level Supply Current:				
I_{CCL}	Buffer, 10K Pull-up OPB665 Buffer, Open-Collector OPB666		5.5	12.0	mA	$V_{CC} = 16\text{ V}$, No Load On Output, $I_F = 0\text{ mA}$
	I_{CCL}	Inverter, 10K Pull-up OPB667 Inverter, Open-Collector OPB668		6.5	12.0	mA
V_{OH}		High Level Output Voltage:				
	Buffer, 10K Pull-up OPB665 Inverter, 10K Pull-up OPB667	$(V_{CC}-1.5)^{(5)}$			V	$I_{OH} = 100\ \mu\text{A}$, $I_F = 10\text{ mA}$
I_{OH}	High Level Output Current:					
	Buffer, Open-Collector OPB666 Inverter, Open-Collector OPB668			100	μA	$V_{CC} = 16\text{ V}$, $V_{OH} = 30\text{ V}$, $I_F = 10\text{ mA}$
V_{OL}	Low Level Output Voltage:					
	Buffer, 10K Pull-up OPB665 Buffer, Open-Collector OPB666			0.4	V	$V_{CC} = 4.5\text{ V}$, $I_{OL} = 16\text{ mA}$, $I_F = 0\text{ mA}^{(4)}$
V_{OL}	Inverter, 10K Pull-up OPB667 Inverter, Open-Collector OPB668			0.4	V	$V_{CC} = 4.5\text{ V}$, $I_{OL} = 16\text{ mA}$, $I_F = 10\text{ mA}$
	t_r, t_f	Output Rise Time, Output Fall Time		30	ns	
t_{PLH}	Propagation Delay, Low-High					$V_{CC} = 5\text{ V}$, $I_F = 0$ or 10 mA , $f = 10\text{ kHz}$, DC = 50%, $R_L = 300\ \Omega$
	Buffer, 10K Pull-up OPB665 Buffer, Open-Collector OPB666		1.0		μs	
	Inverter, 10K Pull-up OPB667 Inverter, Open-Collector OPB668		2.0		μs	
	t_{PHL}	Propagation Delay, High-Low				
t_{PHL}	Buffer, 10K Pull-up OPB665 Buffer, Open-Collector OPB666		2.0		μs	
	Inverter, 10K Pull-up OPB667 Inverter, Open-Collector OPB668		1.0		μs	
	Data Rate	Data Rate		100	kHz	$V_{CC} = 5\text{ V}$, $I_F = 0$ or 10 mA , DC = 50%, $R_L = 300\ \Omega$

(4) Normal application would be with light source blocked, simulated by $I_F = 0\text{ mA}$.

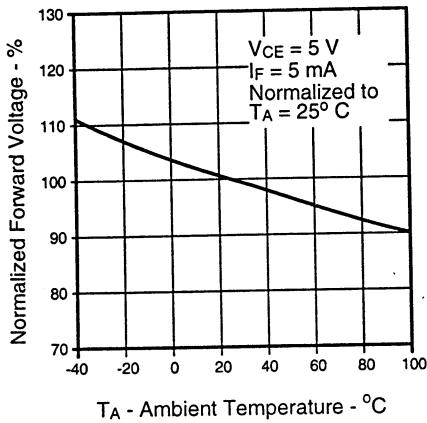
(5) $V_{OH} = V_{CC}-1.5$ for $V_{CC} = 4.5\text{ V}$ to 16 V .

Types OPB665N/T, OPB666N/T, OPB667N/T, OPB668N/T

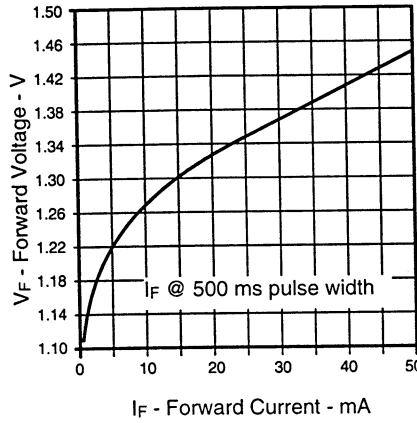
Typical Performance Curves

SLOTTED OPTICAL SWITCHES

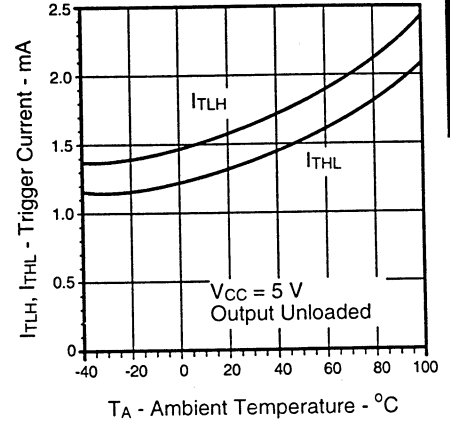
Normalized Forward Voltage vs Ambient Temperature



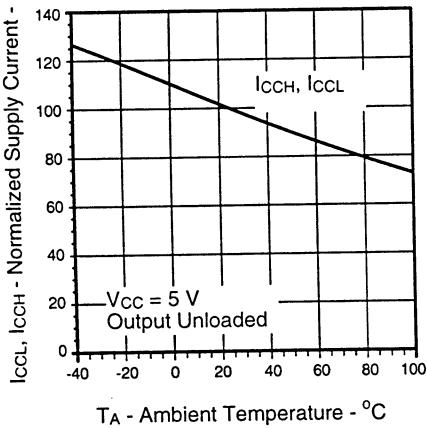
Forward Current vs Forward Voltage Input Diode



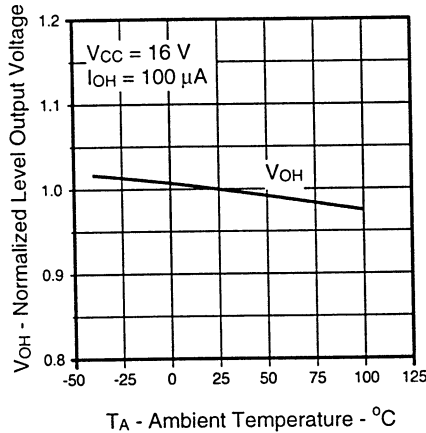
Trigger Current vs Ambient Temperature



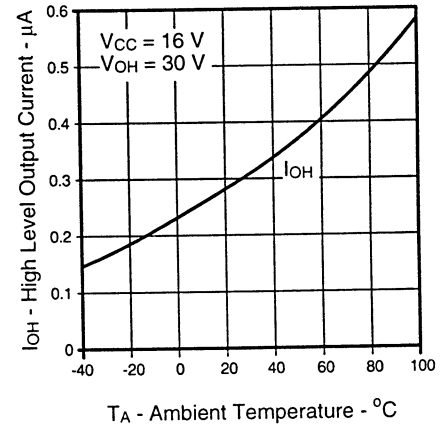
Normalized Supply Current vs Ambient Temperature



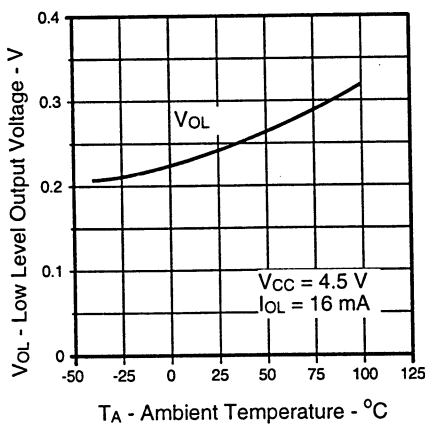
OPB665, OPB667 Normalized High Level Output Voltage vs Ambient Temperature



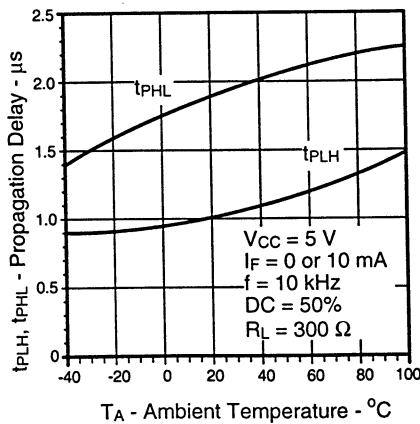
OPB666, OPB668 High Level Output Current vs Ambient Temperature



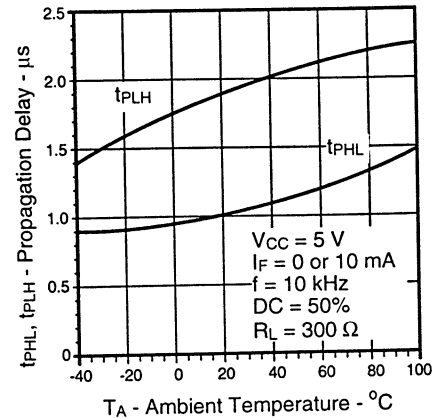
Low Level Output Voltage vs Ambient Temperature



OPB665, OPB666 Propagation Delay vs Ambient Temperature



OPB667, OPB668 Propagation Delay vs Ambient Temperature



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Types OPB665N/T, OPB666N/T, OPB667N/T, OPB668N/T

Typical Performance Curves

